MOSFETs Silicon N-Channel MOS (π-MOSVII)

TK6A80E

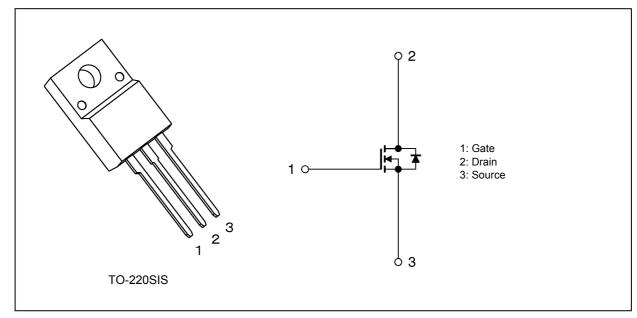
1. Applications

Switching Voltage Regulators

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)} = 1.35 \Omega$ (typ.)
- (2) Low leakage current : $I_{\rm DSS}$ = 10 μA (max) (V_{\rm DS} = 640 V)
- (3) Enhancement mode: V_{th} = 2.5 to 4.0 V (V_{DS} = 10 V, I_D = 0.6 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (T_a = 25 °C unless otherwise specified)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	800	V
Gate-source voltage		V _{GSS}	±30	7
Drain current (DC)	(Note 1)	Ι _D	6	Α
Drain current (pulsed)	(Note 1)	I _{DP}	18	7
Power dissipation (T	_c = 25°C)	PD	45	W
Single-pulse avalanche energy	(Note 2)	E _{AS}	308	mJ
Avalanche current	·	I _{AR}	6	Α
Reverse drain current (DC)	(Note 1)	I _{DR}	6	7
Reverse drain current (pulsed)	(Note 1)	I _{DRP}	18	1
Channel temperature		T _{ch}	150	°C
Storage temperature		T _{stg}	-55 to 150	7
Isolation voltage (RMS)		V _{ISO(RMS)}	2000	V
Mounting torque		TOR	0.6	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	2.78	°C/W
Channel-to-ambient thermal resistance	R _{th(ch-a)}	62.5	°C/W

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 15.5 mH, R_G = 25 Ω , I_{AR} = 6 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±30 V, V_{DS} = 0 V	_	_	±1	μA
Drain cut-off current	I _{DSS}	V_{DS} = 640 V, V_{GS} = 0 V	_	_	10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	800	—	_	V
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 0.6 mA	2.5	—	4.0	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 3 A		1.35	1.7	Ω

6.2. Dynamic Characteristics (Ta = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V_{DS} = 25 V, V_{GS} = 0 V, f = 1 MHz	_	1350	_	pF
Reverse transfer capacitance	C _{rss}		_	10	_	
Output capacitance	C _{oss}	1	_	110	_	
Gate resistance	r _g	V _{DS} = OPEN, f = 1 MHz	_	4.0	_	Ω
Switching time (rise time)	tr	See Fig. 6.2.1.	_	20	_	ns
Switching time (turn-on time)	t _{on}	1	_	55	_	
Switching time (fall time)	t _f	1	_	15	_	
Switching time (turn-off time)	t _{off}]		85	_	
MOSFET dv/dt ruggedness	dv/dt	$V_{DD} = 0$ to 400 V, $I_D = 6$ A	20	_	_	V/ns

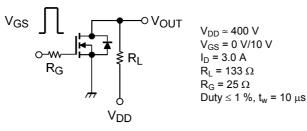


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 400 \text{ V}, \text{ V}_{GS}$ = 10 V, I _D = 6 A	_	32	_	nC
Gate-source charge 1	Q _{gs1}		_	10	_	
Gate-drain charge	Q _{gd}			12		

6.4. Source-Drain Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	V _{DSF}	I _{DR} = 6 A, V _{GS} = 0 V	_	—	-1.7	V
Reverse recovery time	t _{rr}	I _{DR} = 6 A, V _{GS} = 0 V	_	1100	—	ns
Reverse recovery charge	Q _{rr}]-dI _{DR} /dt = 100 A/μs	_	8	_	μC
Peak reverse recovery current	I _{rr}		_	18	_	A

7. Marking (Note)

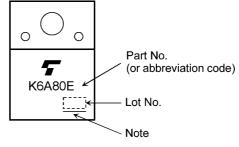
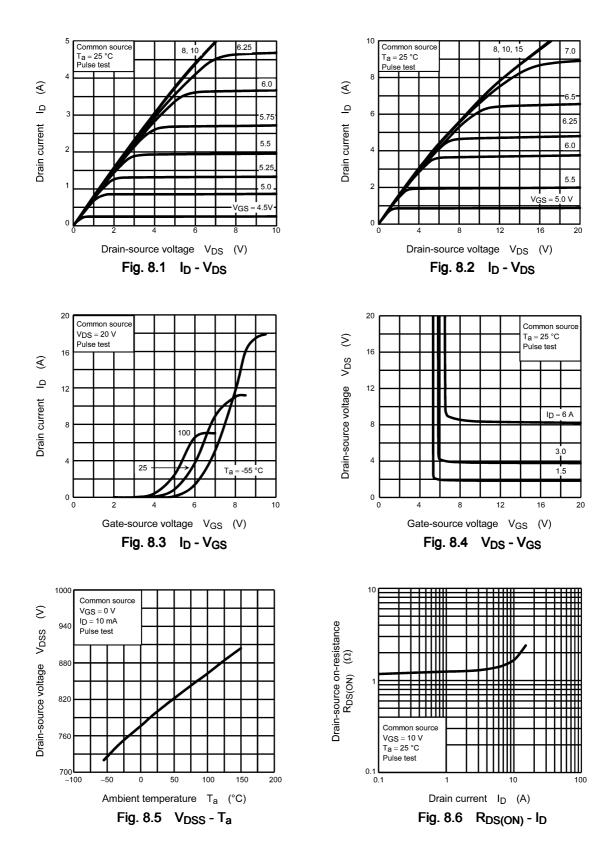


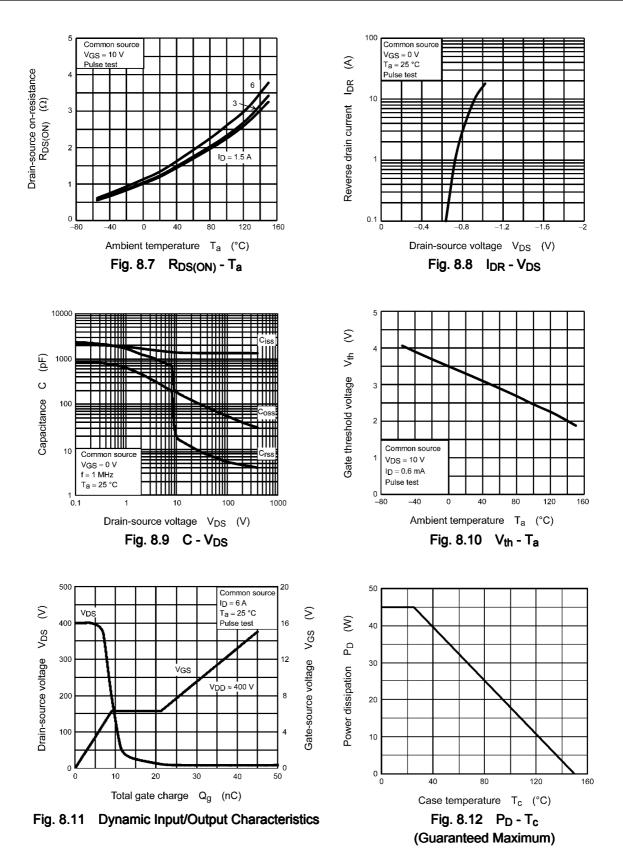
Fig. 7.1 Marking

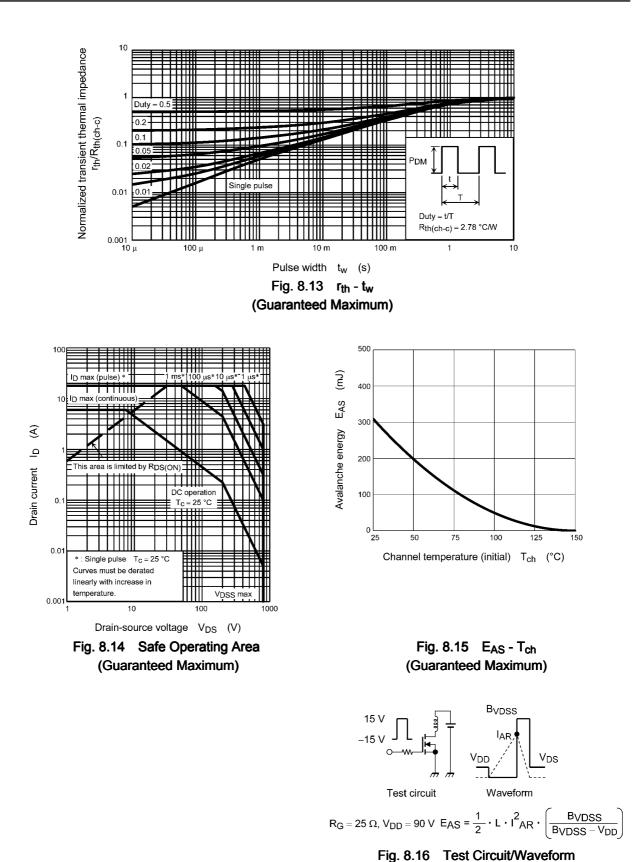
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8. Characteristics Curves (Note)





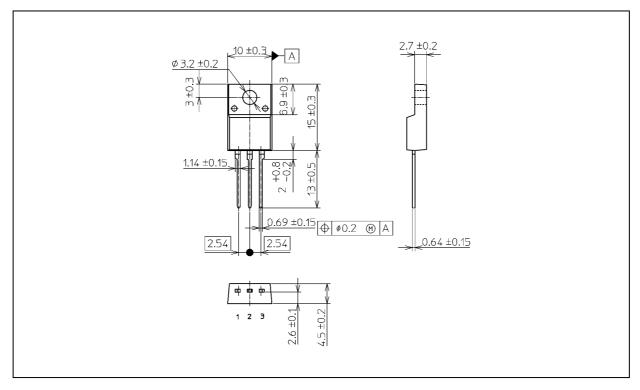


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

TK6A80E

Package Dimensions

Unit: mm



Weight: 1.7 g (typ.)

Package Name(s)			
JEITA: SC-67			
TOSHIBA: 2-10U1S			
Nickname: TO-220SIS			

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